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# One-step hydrothermal preparation of Ce-doped MoO<sub>3</sub> nanobelts with enhanced gas sensing properties†

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Rare earth ions are considered as the ideal dopants to modify the crystal structure, electronics structure, and gas sensing performance of metal oxides semiconductors. In this paper, Ce-doped MoO<sub>3</sub> nanobelts were successfully synthesized *via* a one-step hydrothermal method. The morphology and microstructure were characterized by X-ray diffraction (XRD), field emission scanning electron microscopy (FESEM), energy-dispersive X-ray spectroscopy (EDS), and X-ray photoelectron spectra (XPS). FESEM images demonstrate that the as-prepared products are uniform nanobelts with length of about 20 μm and width of 100–200 nm. EDS, XRD, and XPS spectroscopy show that Ce atoms were uniformly distributed in the crystal structure of MoO<sub>3</sub> nanobelts. In comparison with pure samples, Ce-doped MoO<sub>3</sub> nanobelts exhibited superior trimethylamine (TMA) sensing properties at a lower working temperature. The effects of Ce-doping on the trimethylamine sensing performance of MoO<sub>3</sub> nanobelts were discussed based on the experimental results. In addition, this study provided insights and strategies for designing high performance TMA gas sensors.

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## Introduction

Trimethylamine (TMA) is widely used in many fields as a raw material in the chemical industry. It exists as a colorless gas with a fishy ammonia-like odour at normal temperature. Exposure to TMA gas will result in coughing, irritation of the upper respiratory system, difficulty in breathing and lung oedema.<sup>1,2</sup> Thus, it is very important to detect TMA accurately and quickly. Using gas sensors based on metal oxide semiconductors (MOS) is a typical method for TMA detection, such as P. M. Perillo *et al.* prepared TiO<sub>2</sub> membrane nanotubes to detect TMA within a concentration range of 40–400 ppm.<sup>3</sup> Y. H. Cho *et al.* have synthesized WO<sub>3</sub> hollow spheres by ultrasonic spray pyrolysis of a citric-acid-containing precursor solution, which showed high response to TMA gas.<sup>4</sup>

As a wide band gap semiconductor material, molybdenum trioxide (MoO<sub>3</sub>) has corner/edge/face-sharing MoO<sub>6</sub> octahedron units which are capable of forming zigzag chain and unique layer/tunnel structure. It has been investigated over the past decades due to its distinctive properties of electrochromism, thermochromism and photochromism, as smart materials, catalysts and host materials for intercalation.<sup>5–9</sup> Furthermore, many researchers have reported the gas-sensing properties of MoO<sub>3</sub>-based gas sensors.<sup>10–13</sup> For instance, using spray pyrolysis

method, R. Pandeewari *et al.* prepared MoO<sub>3</sub> thin films with excellent TMA sensing performance.<sup>14</sup> J. H. Lee *et al.* reported MoO<sub>3</sub> nanoplates as TMA sensing material *via* ultrasonic spray pyrolysis technique.<sup>15</sup> Chu *et al.* prepared MoO<sub>3</sub> micro-rods and the detection limit to trimethylamine was 0.01 ppm with a sensitivity of 1.5 at 300 °C.<sup>16</sup> Compared with other morphologies, one-dimensional (1-D) nanostructures such as nanowires, nanobelts, and nanotubes have been demonstrated to be promising candidates for ultrasensitive sensors because of their single crystal nanostructure, high surface-to-volume ratios, specially physical and chemical properties.<sup>17–22</sup> S. Yang *et al.* reported ultralong MoO<sub>3</sub> nanobelts with length of 200 μm with excellent TMA sensing performance.<sup>23</sup> Our group have synthesized MoO<sub>3</sub> nanobelts decorated with Au nanoparticles, which exhibited highly sensitive and selective properties to trimethylamine gas.<sup>24</sup> Obviously, further investigation is necessary for enhancing TMA sensing performance of 1-D MoO<sub>3</sub> nanomaterials.

Doping, the addition of specific extrinsic element, is another effective approach to enhance the gas-sensing properties of metal oxide semiconductors.<sup>25–31</sup> In particular, cerium (Ce), as a dopant to improve gas sensing performance of metal oxide, has caused widely concern and achieved certain achievements, such as Ce-doped In<sub>2</sub>O<sub>3</sub> nanospheres,<sup>32</sup> Ce-doped SnO<sub>2</sub> hollow nanofibers,<sup>33</sup> Ce-doped ZnO thin film,<sup>34</sup> Ce-doped iron oxide.<sup>35</sup> However, to the best of our knowledge, there is a few reports on the TMA sensing characteristics of Ce-doped 1-D MoO<sub>3</sub> nanomaterials. Based on the above mentioned advantages of 1-D MoO<sub>3</sub> nanomaterials for gas sensing, as well as those associated

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with Ce doping, we synthesized pure and Ce-doped MoO<sub>3</sub> nanobelts by a one-step hydrothermal route. The morphology, microstructure and chemical state of as-obtained samples are characterized. In addition, the TMA sensing properties of pure and Ce-doped MoO<sub>3</sub> nanobelts were tested. Experimental results show that the introduction of Ce-doping is an effective way to enhance the sensing characteristic MoO<sub>3</sub> nanobelts toward TMA gas.

## Experimental

### Synthetic procedures

All the reagents we used in this experiment were of analysis grade and used without further purification. In a typical hydrothermal synthesis route, MoO<sub>3</sub> powders were firstly obtained by calcining (NH<sub>4</sub>)<sub>6</sub>Mo<sub>7</sub>O<sub>24</sub>·4H<sub>2</sub>O at 500 °C for 240 min. Then, 3.6 g of as-prepared MoO<sub>3</sub> powders were dissolved in 27 mL of 30% aqueous H<sub>2</sub>O<sub>2</sub> under vigorous stirring. Subsequently, a mixture solution of certain amount of cerium nitrate (with a mole ratio of 4%) dissolved in 13 mL concentrated nitric acid and 85 mL deionized water was added. After stirring 20 minutes at room temperature, the above solution was transferred into a Teflon-lined stainless-steel autoclave and under heat treatment at 170 °C for 48 h. After the hydrothermal reaction, the autoclave cooled naturally down to room temperature. The precipitates were collected by centrifugation, washed several times with distilled water and absolute ethanol, respectively, and dried at 60 °C for 12 h. For comparison, the pure MoO<sub>3</sub> nanobelts were also synthesized with the same techniques without adding cerium nitrate. The gas sensing properties were tested based on a computer-controlled WS-30A system with a static process.<sup>24</sup> For the target gases obtained from liquid, the concentration of target gas was calculated by the following formula,

$$C = (22.4 \times \rho \times d \times V_1) / (M \times V_2) \quad (1)$$

where  $C$  (ppm) is the target gas concentration,  $\rho$  (g mL<sup>-1</sup>) is the density of the liquid,  $d$  is the purity of the liquid,  $V_1$  (μL) is the volume of the liquid,  $V_2$  (L) is the volume of the glass chamber, and  $M$  (g mol<sup>-1</sup>) is the molecular weight of the liquid. By the formula, we can calculate the different gas concentrations.

### Characterization

The crystal structure and phase composition of as-prepared samples were identified by X-ray diffraction (XRD, Bruker D8 Advance) using CuKα1 radiation ( $\lambda = 0.15406$  nm) at 30 kV and 40 mA at a scanning rate of 2° at 2 $\theta$  min<sup>-1</sup>. The morphology and nanostructure of the products were characterized using FEI Sirion 200 field emission gun scanning electron microscope (FESEM, Hitachi S4800), and transmission electron microscopy (TEM, Hitachi H-800). The energy-dispersive X-ray spectroscopy (EDS) analysis was performed by the FESEM attachment. The X-ray photoelectron spectra (XPS) were obtained on an X-ray photoelectron spectrometer (PHI 5300) to determine the electronic structure of the surface of the Ce-doped MoO<sub>3</sub> nanobelts.

## Results and discussion

### Structure characterization

The representative morphology and microstructure of as-obtained samples are observed by FESEM. Fig. 1(a) illustrates typical FESEM image of the MoO<sub>3</sub> powders obtained from (NH<sub>4</sub>)<sub>6</sub>Mo<sub>7</sub>O<sub>24</sub>·4H<sub>2</sub>O calcined at 500 °C. It can be seen that the samples are irregularly shaped particles with micron-scale size. After one-step hydrothermal treatment, the surface morphology of the pure MoO<sub>3</sub> samples could be clearly observed from typical FESEM image (Fig. 1(b)). From the overall morphology, it can be found that the products are uniform nanobelts with an average length of about 20 μm and width of 100–200 nm. From Fig. 1(c), the morphology of Ce-doped MoO<sub>3</sub> nanobelts has no obvious variation. In our experiments, the MoO<sub>3</sub> powders were dissolved in H<sub>2</sub>O<sub>2</sub> and a transparent yellow solution was obtained after magnetic stirring. In this process, the solution-soluble precursor compound MoO<sub>2</sub>(OH)(OOH) could form easily.<sup>36,37</sup> In the subsequent hydrothermal growth stage, tiny MoO<sub>3</sub> nuclei were generated by dehydration of the dissolved yellow Mo-complex. The formation mechanism of α-MoO<sub>3</sub> nanobelts can be explained by the anisotropic growth of material itself. The strong preferential growth of (010) crystal plane in the [001] direction of orthorhombic α-MoO<sub>3</sub> forming one-dimensional structure is determined by its structural characteristics.<sup>38–40</sup> In the structure of α-MoO<sub>3</sub>, distorted MoO<sub>6</sub> octahedra interconnect *via* co-edges in [001] direction (*c*-axis) and co-vertices in the [100] direction (*a*-axis). The interaction of the adjacent layers in the *b*-axis depends on the weak van der Waals force, whereas that replayed on the strong covalent bond in the *c*-axis. If the MoO<sub>3</sub> crystal grows in the [001] direction, the system will release more energy, in other words, the growth in the *c*-axis is favorable in accordance with principle of minimum energy. The energy-dispersive X-ray spectroscopy (EDS) analysis was used to further explore the existence of Ce in the doped samples. The corresponding EDS elemental mappings (Fig. 1(d–f)) indicate that the as-obtained nanobelts are composed of Mo, O, and Ce elements, and as expected, Ce is uniform distribution in the elemental mapping of Ce-doped MoO<sub>3</sub> nanobelts, which

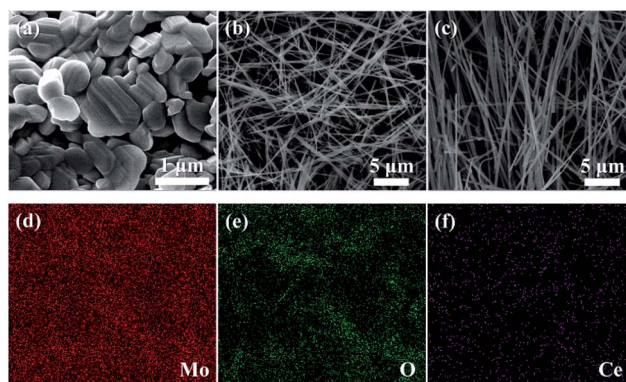


Fig. 1 (a) Typical FESEM image of MoO<sub>3</sub> powders; (b and c) FESEM images of pure and Ce-doped MoO<sub>3</sub> nanobelts, and (d–f) EDS elemental mapping of Ce-doped MoO<sub>3</sub> nanobelts (Mo, O, and Ce).



provide the direct evidence of the successful doping of Ce into the bulk  $\text{MoO}_3$ .

The phase purity of as-synthesized samples was characterized by XRD. As shown in Fig. 2(a), all the peaks in XRD pattern are readily agree with orthorhombic  $\alpha\text{-MoO}_3$  (corresponding JCPDS card No. 35-0609). For the as-prepared Ce-doped  $\text{MoO}_3$  nanobelts, no additional diffraction peaks of cerium oxide and its related secondary or impurity phase were detected in the Fig. 2(b). The results indicated that Ce could be incorporated into the lattice of  $\text{MoO}_3$  without affecting the orthorhombic structure of molybdenum trioxide. In order to investigate the effect of doping on the phase structures of the  $\text{MoO}_3$  nanobelts, the (040) and (021) diffraction peaks were monitored, as shown in the inset of Fig. 2. It can be seen that the (040) and (021) diffraction peaks of Ce-doped  $\text{MoO}_3$  shift slightly compared to the pure  $\text{MoO}_3$ . The result proved that the incorporation of Ce ions led to lattice deformation due to the difference between ionic radius of Ce [0.87 Å] and Mo [0.65 Å]. Furthermore, it can be observed that the half-width of diffraction peaks of Ce-doped  $\text{MoO}_3$  are slightly increase compared with those of pure  $\text{MoO}_3$ . The average grain sizes are estimated using the Scherrer formula, which are about 27.64 and 23.76 nm for pure and doped samples, respectively, confirming that Ce-doping can cause the inhibition effect on crystallite size from growing up during the hydrothermal treatment, which is consistent with previous research.<sup>41–43</sup>

In order to investigate the chemical composition and valence state of elements, XPS analysis was characterized and the patterns are shown in Fig. 3. The XPS survey spectrum for Ce-doped  $\text{MoO}_3$  nanobelts is presented in Fig. 3(a). The spectrum exhibits the preference of all expected core levels due to Mo 3d, O 1s, Ce 3d and C 1s. And the corresponding high resolution spectra are shown in Fig. 3(b–d). The doublets of Mo  $3d_{5/2}$  and Mo  $3d_{3/2}$  peaks, located at 232.3 and 235.4 eV in Fig. 3(b), correspond to  $\text{Mo}^{6+}$  in  $\text{MoO}_3$  stoichiometric.<sup>44</sup> Fig. 3(c) displays the O 1s XPS spectrum of Ce-doped  $\text{MoO}_3$  nanobelts. Two

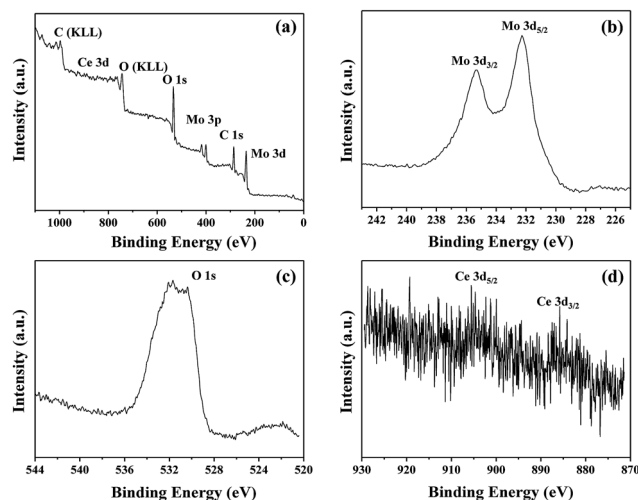


Fig. 3 XPS spectra of Ce-doped  $\text{MoO}_3$  nanobelts. (a) Survey spectrum; (b) Mo 3d binding energy spectrum; (c) O 1s binding energy spectrum; (d) Ce 3d binding energy spectrum.

components are observed: a low binding energy (530.5 eV) is originated from the lattice oxygen in  $\text{MoO}_3$ ,<sup>45–47</sup> and that at high binding energy (531.6 eV) is usually assigned to the oxygen vacancies in the matrix of metal oxide,<sup>48–50</sup> formed due to Ce ions substitution. The results indicated that Ce-doping modified the surface state of  $\text{MoO}_3$  nanobelts by producing oxygen vacancies, and such defects will have great influence on the gas sensing properties. Fig. 3(d) shows the Ce 3d XPS of the Ce-doped  $\text{MoO}_3$  sample. It was reported that the Ce 3d spectra can be attributed to two sets of spin orbital multiples,  $3d_{5/2}$  and  $3d_{3/2}$ .<sup>51,52</sup> As shown in Fig. 4(d), the presence of  $\text{Ce}^{3+}$  in the hybrid is confirmed by the appearance of weak signals at 885.6 and 905.1 eV.<sup>53–55</sup> However, the diffraction peaks of  $\text{Ce}^{3+}$  were not observed from the XRD pattern in Fig. 2, indicating that the  $\text{Ce}^{3+}$  was incorporated into the lattice of  $\text{MoO}_3$  and had a very low content (4 mol%).

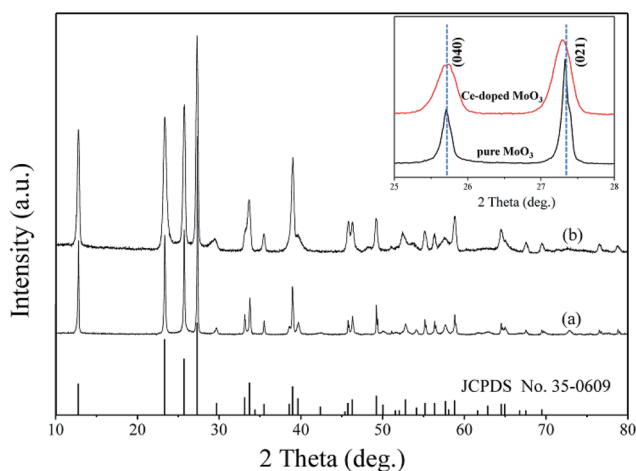


Fig. 2 XRD patterns of (a) pure and (b) Ce-doped  $\text{MoO}_3$  nanobelts. The inset is the comparison of (040) and (021) peaks from XRD patterns.

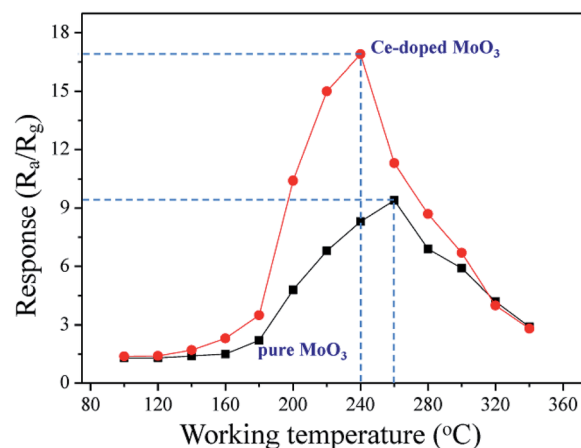


Fig. 4 Sensor response of pure and Ce-doped  $\text{MoO}_3$  nanobelts to 50 ppm TMA gas versus working temperature.



## Gas-sensing properties

As is well-known, the operating temperature is a very important parameter for gas sensors based on metal oxide. To confirm the optimum operating temperature of as-synthesized samples, we investigate the variations of the sensor response as a function of the operating temperature. As shown in Fig. 4, it can be observed that sensor based on pure MoO<sub>3</sub> nanobelts show relatively low response to 50 ppm TMA at the operating temperature in the range from 100 to 340 °C, with the maximum response of 4.6 at 280 °C. For compact, sensor response of Ce-doped MoO<sub>3</sub> nanobelts displays significant increase, reaching the maximum value of 17.4 at the operating temperature of 240 °C. Compared with pure MoO<sub>3</sub> nanobelts, the optimum operating temperature of the Ce-doped MoO<sub>3</sub> nanobelts sensor has a notable decrease. These results demonstrate that the Ce-doped MoO<sub>3</sub> nanobelts display about fourfold enhancement in sensor response compared to pure MoO<sub>3</sub>, which is caused by the promotion effect of Ce-doping.

Fig. 5(a) illustrates the dynamic response and recovery curves of the sensor based on pure and Ce-doped MoO<sub>3</sub> nanobelts to different TMA concentrations (from 5 to 500 ppm) at 260 and 240 °C, respectively. From the curves, it is obviously found that

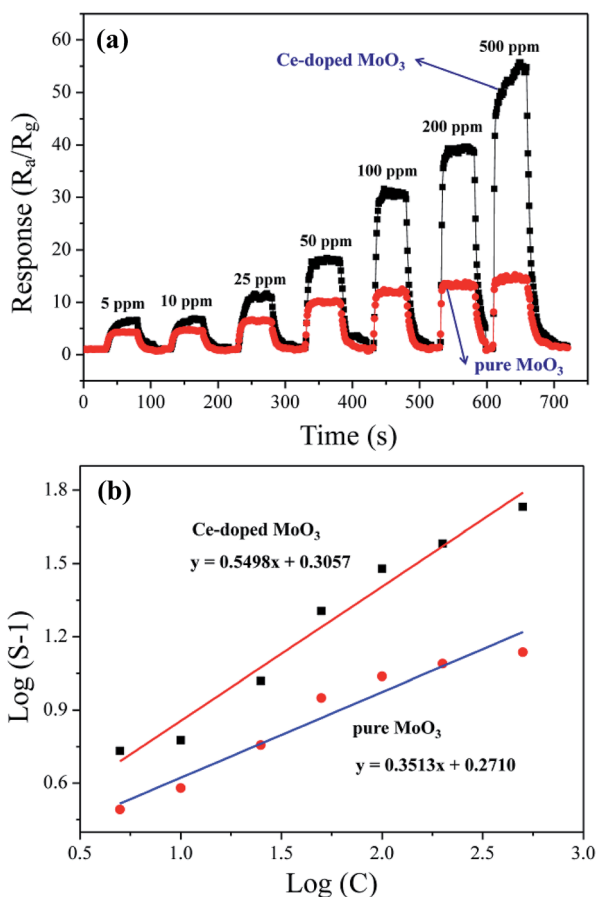


Fig. 5 (a) Relationships between sensor response of pure and Ce-doped MoO<sub>3</sub> nanobelts and TMA concentration and (b) the corresponding  $\log(S - 1)$  vs.  $\log(C)$  of the sensor based on pure and Ce-doped MoO<sub>3</sub> nanobelts.

the response increased with an increase in TMA concentration. Specifically, the sensor based on Ce-doped MoO<sub>3</sub> nanobelts exhibited higher response to TMA at different concentrations compared with that of pure MoO<sub>3</sub> nanobelts. Previous research suggests that the concentration ( $C$ ) of detected gas and the corresponding response ( $S$ ) of metal oxide can be empirically represented as  $S = a[C]^b + 1$ . Generally for n-type semiconductor, the exponent  $b$  has an ideal value of 0.5 to 1.<sup>56–58</sup> As shown in Fig. 5(b), the straight lines were the calibration curves and the experimental data were fitted as:

$$y = 0.5498x + 0.3057 \quad (2)$$

$$y = 0.3513x + 0.2710 \quad (3)$$

where  $y$  is  $\log(S - 1)$  and  $x$  is  $\log(C)$ . The response of both sensors have good linear relationship with the TMA concentration (5–500 ppm range) in logarithmic forms, which is in good agreement with the theory of power laws for semiconductor sensors.<sup>59</sup> The slope of Ce-doped MoO<sub>3</sub> nanobelts sensor is 0.5498, which is larger than that of pure MoO<sub>3</sub> nanobelts (0.3513). It indicates that the Ce-doped MoO<sub>3</sub> nanobelts sensor is more sensitive than the pure one, and the response of Ce-doped MoO<sub>3</sub> nanobelts based sensor increase faster than that of pure one accompanied with the increase of gas concentration. Gas sensing tests highlight potential application of the Ce-doped MoO<sub>3</sub> nanobelts in detecting TMA vapor.

Fig. 6(a) illustrates the reproducibility of the sensor based on Ce-doped MoO<sub>3</sub> nanobelts, revealing that the sensor maintains its initial response amplitude without obvious changes upon three successive sensing measurements to 50 ppm of TMA. In addition, within the 3 cycles, the sensor still maintains fast response and recovery state, which are demanded for practical application. The response and recovery times of Ce-doped MoO<sub>3</sub> nanobelts sensor to 50 ppm TMA are less than 10 and 20 s, respectively, accords with practical application of gas sensors. Moreover, the response as a function of the number of testing days was investigated and shown in Fig. 6(b). The result further indicated the splendid long-term stability of the sensor based on Ce-doped MoO<sub>3</sub> nanobelts.

Selectivity is an important indicator of gas sensors in practical applications. The gas responses of Ce-doped MoO<sub>3</sub> nanobelts towards different testing gases of 50 ppm TMA, ammonia, acetone, benzene, and ethanol are tested at 240 °C. As shown in Fig. 7, sensor response towards TMA is significantly higher than those of other gases. The selectivity of TMA is evaluated by the selectivity coefficient, which can be defined as:

$$K_{\text{TMA}} = S_{\text{TMA}}/S_{\text{gas}} \quad (4)$$

where  $S_{\text{TMA}}$  and  $S_{\text{gas}}$  are sensor response towards TMA and any other gas. The selectivity coefficients for Ce-doped MoO<sub>3</sub> nanobelts based sensor were 5.2 to ammonia, 9.2 to acetone, 11.1 to benzene, and 6.0 to ethanol, indicating that Ce-doped MoO<sub>3</sub> nanobelts exhibit good selectivity to TMA gas.



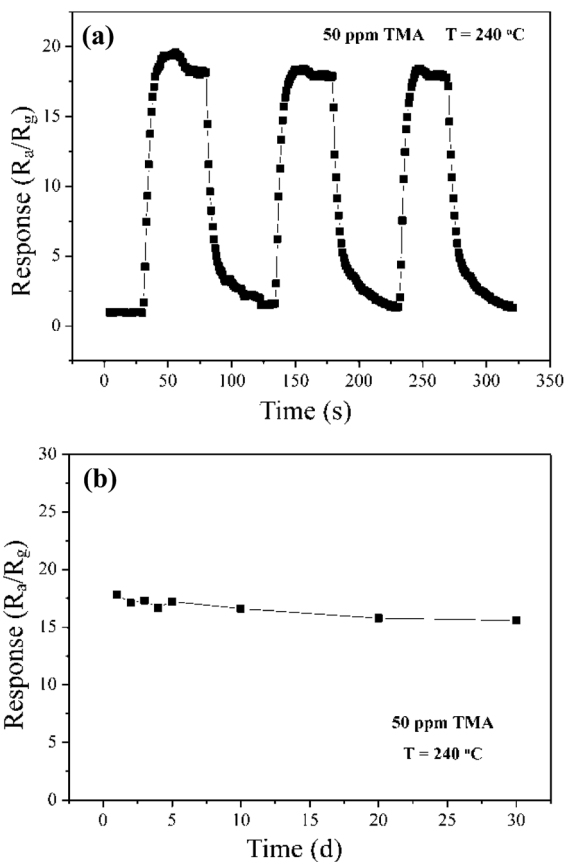


Fig. 6 (a) Three periods of response curve of Ce-doped MoO<sub>3</sub> nanobelts to 50 ppm TMA at 240 °C and (b) long-term stability of Ce-doped MoO<sub>3</sub> nanobelts sensor on successive exposure to 50 ppm TMA at 240 °C.

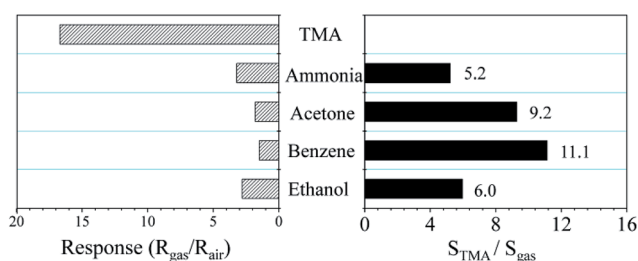


Fig. 7 Sensor response of Ce-doped MoO<sub>3</sub> nanobelts towards 50 ppm TMA, ammonia, acetone, benzene, and ethanol at 240 °C and the selectivity to TMA ( $S_{\text{TMA}}$  and  $S_{\text{gas}}$ , gas responses to TMA and other gases, respectively).

As generally mentioned earlier, the gas sensing mechanism of MoO<sub>3</sub>-based sensors belongs to the surface-controlled type, which is based on the change in sensor resistance, mainly caused by the adsorption and desorption of gas molecules on the surface of MoO<sub>3</sub> structure.<sup>60–62</sup> Fig. 8 shows the adsorption and reaction model of the sensing process on the surface of pure and Ce-doped MoO<sub>3</sub> nanobelt. Generally, when MoO<sub>3</sub> nanobelts are exposed to air atmosphere, oxygen molecules are adsorbed on the surface of nanobelts, and capture electron in

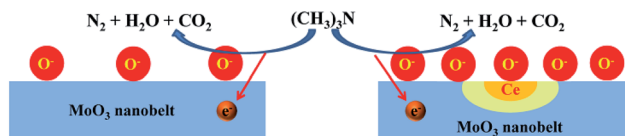
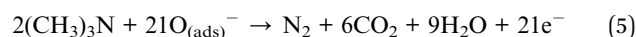
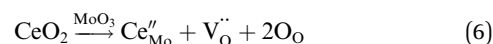


Fig. 8 Adsorption and reaction model of the sensing process on the surface of pure and Ce-doped MoO<sub>3</sub> nanobelt.

the surface region, forming reactive oxygen species O<sub>(ads)</sub><sup>-</sup>. When injected into testing chamber, TMA gases (reducing gas) can react with reactive oxygen species O<sup>-</sup> and release the trapped electrons back to the conduction band of MoO<sub>3</sub>, leading to the decrease of sensor resistance, which can be written as:<sup>63–66</sup>



In this work, the huge improvement in gas response by Ce-doping may be due to the promotion effect of oxygen vacancy, which will be produced when Ce atom replaces Mo atom. The forming of oxygen vacancy with double positive charge can be expressed by the Kröger–Vink notation:<sup>67</sup>



This result accords with the experiment of XPS (Fig. 3(c)). Based on the above formula, the relatively higher concentration surface oxygen vacancies can be formed due to Ce ions substitution, which is very important to the adsorption of oxygen on the surface of MoO<sub>3</sub> nanobelts. On exposure to air, oxygen vacancies will be reduced by the incorporation of gaseous O<sub>2</sub>. Furthermore, as one of the most important rear-earth compounds, ceria has widely application in automobile exhaust catalysts for its stability to take and release oxygen under oxidizing and reducing conditions.<sup>68,69</sup> Accordingly it is also conducive to more oxygen adsorption. Thus, we believe that the Ce site works as O<sub>2</sub> absorbers and to some extent generate O<sup>-</sup> adsorption sites around Ce atoms, as shown in Fig. 8. Accordingly more electrons produced by the reaction between TMA and O<sup>-</sup> are released back to the conduction band of nanobelts, leading to higher gas response.

## Conclusions

In summary, we developed a facile one-step hydrothermal route for the synthesis of pure and Ce-doped MoO<sub>3</sub> nanobelts. Characterizations based on XRD, EDS, and XPS displayed that Ce atoms replaced into the crystals of MoO<sub>3</sub> without destroying the original crystal structure. The Ce-doping is very important to the adsorption of oxygen on the surface of MoO<sub>3</sub> nanobelts, which is conducive to the promotion of TMA sensing properties, including lower operating temperature and enhanced gas response. Therefore, it is expected Ce-doped MoO<sub>3</sub> nanobelts may provide a new pathway to develop novel TMA gas sensors.



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